



**SBR3U30P1** 

### 3.0A SBR SUPER BARRIER RECTIFIER POWERDI123

#### **Features**

- Ultra-Low Forward Voltage Drop
- Superior Reverse Avalanche Capability
- Patented Interlocking Clip Design for High Surge Current Capacity
- Patented Super Barrier Rectifier (SBR<sup>®</sup>) Technology
- Soft, Fast Switching Capability
- +150°C Operating Junction Temperature
- ±16KV ESD Protection (HBM, 3B)
- ±25KV ESD Protection (IEC61000-4-2 Level 4, Air Discharge)
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Qsuffix) part. A listing can be found at <a href="https://www.diodes.com/products/automotive/automotive-products/">https://www.diodes.com/products/automotive/automotive-products/</a>.
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

### **Mechanical Data**

- Case: PowerDI<sup>®</sup>123
- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Polarity Indicator: Cathode Band
- Terminals: Matte Tin Finish Annealed over Copper Leadframe Solderable per MIL-STD-202, Method 208 63
- Weight: 0.018 grams (Approximate)



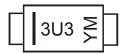
## **Ordering Information** (Note 4)

Part Number	Case	Packaging
SBR3U30P1-7	PowerDI123	3000/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3), compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

### **Marking Information**



3U3 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: G = 2019) M = Month (ex: 9 = September)

Date Code Key

,	Year	2006		2019	2020	2021	2022	2023	2024	2025	2026	2027	2028
(	Code	T		G	Н	-	J	K	L	М	N	0	Р
N	onth	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
	Code	1	2	3	4	5	6	7	8	9	0	N	D



### **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	$V_{RRM}$		
Working Peak Reverse Voltage	V <sub>RWM</sub>	30	V
DC Blocking Voltage	V <sub>RM</sub>		
RMS Reverse Voltage	V <sub>R(RMS)</sub>	21	V
Average Rectified Output Current (See Figure 1)	lo	3.0	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I <sub>FSM</sub>	75	A
Non-Repetitive Avalanche Energy	Eas	105	mJ
$(T_J = +25^{\circ}C, I_{AS} = 5A, L = 8.5mH)$	LAS	103	1110
Repetitive Peak Avalanche Energy (1µs, +25°C)	P <sub>ARM</sub>	1,100	W

## **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Maximum Thermal Resistance Thermal Resistance Junction to Soldering (Note 5) Thermal Resistance Junction to Ambient (Note 6) Thermal Resistance Junction to Ambient (Note 7)	R <sub>0</sub> JS R <sub>0</sub> JA R <sub>0</sub> JA	5 178 123	°C/W
Operating and Storage Temperature Range (Note 8)	T <sub>J</sub> , T <sub>STG</sub>	-65 to +150	°C

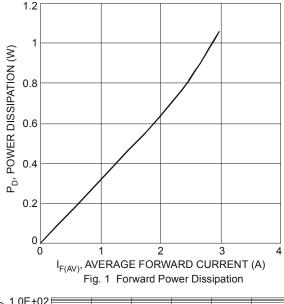
# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

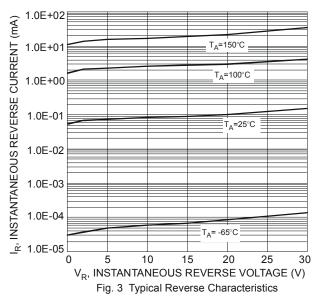
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 8)	V <sub>(BR)R</sub>	30	_	_	V	I <sub>R</sub> = 400μA
Forward Voltage Drop	VF	_	0.28 0.31 0.39 0.20 0.23 0.35	0.32 0.35 0.43 0.23 0.26 0.38	V	$\begin{split} I_F &= 0.5A, \ T_J = +25^{\circ}C \\ I_F &= 1.0A, \ T_J = +25^{\circ}C \\ I_F &= 3.0A, \ T_J = +25^{\circ}C \\ I_F &= 0.5A, \ T_J = +125^{\circ}C \\ I_F &= 1.0A, \ T_J = +125^{\circ}C \\ I_F &= 3.0A, \ T_J = +125^{\circ}C \\ \end{split}$
Leakage Current (Note 8)	I <sub>R</sub>	_	70 150 6 12	150 400 15 20	μΑ μΑ mA mA	$V_R = 5V$ , $T_J = +25^{\circ}C$ $V_R = 30V$ , $T_J = +25^{\circ}C$ $V_R = 5V$ , $T_J = +125^{\circ}C$ $V_R = 30V$ , $T_J = +125^{\circ}C$

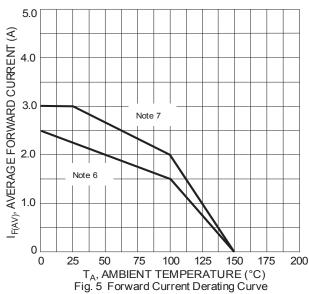
Notes:

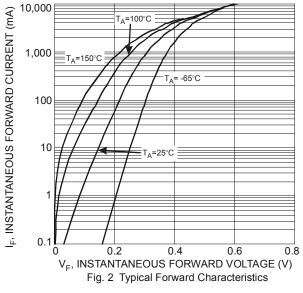
- 5. Theoretical  $R_{\text{0JS}}$  calculated from the top center of the die straight down to the PCB cathode tab solder junction.
- 6. FR-4 PCB, 2 oz. Copper, minimum recommended pad layout per http://www.diodes.com/package-outlines.html.
  7. Polymide PCB, 2 oz. Copper, minimum recommended pad layout per http://www.diodes.com/package-outlines.html.
- 8. Short duration pulse test used to minimize self-heating effect.

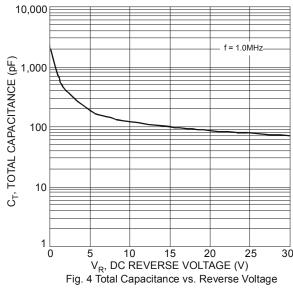


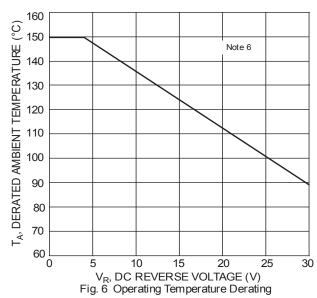




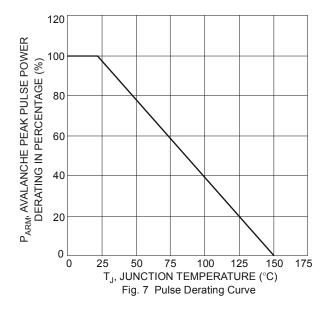












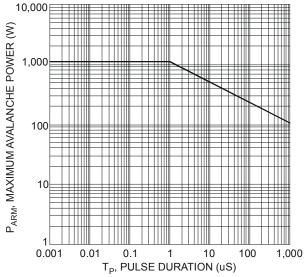


Fig. 8 Maximum Avalanche Power Curve

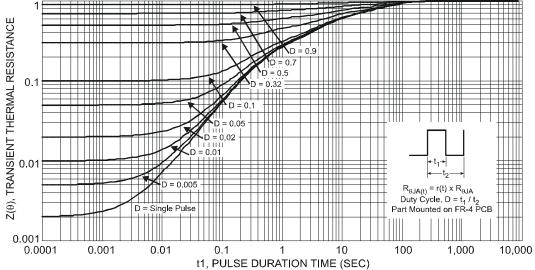
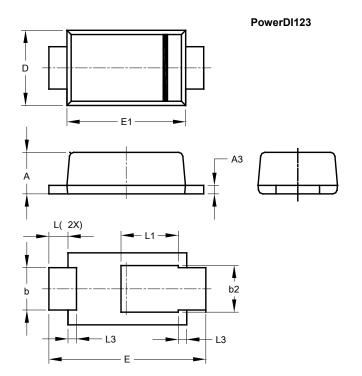


Fig. 9 Transient Thermal Resistance



## **Package Outline Dimensions**

 $Please see \ http://www.diodes.com/package-outlines.html \ for \ the \ latest \ version.$ 

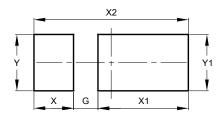


PowerDI123						
Dim	Min	Max	Тур			
Α	0.93	1.00	0.98			
<b>A3</b>	0.15	0.25	0.20			
b	0.85	1.25	1.00			
b2	1.025	1.125	1.10			
D	1.63	1.93	1.78			
Е	3.50	3.90	3.70			
E1	2.60	3.00	2.80			
L	0.40	0.50	0.45			
L1	1.25	1.40	1.35			
L3	0.125	0.275	0.20			
All Dimensions in mm						

## **Suggested Pad Layout**

 $\label{prop:lease} Please see \ http://www.diodes.com/package-outlines.html \ for \ the \ latest \ version.$ 

### PowerDI123



Dimensions	Value (in mm)		
G	0.65		
Х	1.05		
X1	2.40		
X2	4.10		
Y	1.50		
Y1	1.50		



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